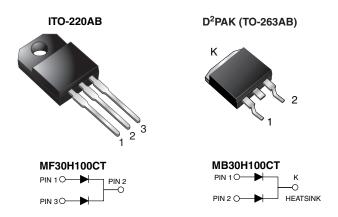


MB30H100CT, MF30H100CT

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _{RRM}	100 V				
I _{FSM}	275 A				
V _F	0.67 V				
I _R	5.0 µA				
T _J max.	175 °C				
Package	ITO-220AB, D ² PAK (TO-263AB)				
Circuit configuration	Common cathode				

FEATURES

Power pack

- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,....)

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MB30H100CT MF30H100CT		UNIT	
Device marking code		MBRB30H100CT	MBRF30H100CT		
Maximum repetitive peak reverse voltage	V _{RRM}	100			
Working peak reverse voltage	V _{RWM}	100		V	
Maximum DC blocking voltage	V _{DC}	100			
Maximum average forward rectified current total de		30			
(fig.1) per dio	de I _{F(AV)}	1	5		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		275		A	
Peak repetitive reverse surge current per diode at t_p = 2.0 µs, 1 k	kHz I _{RRM}	I _{RRM} 1.0			
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175		°C	
Isolation voltage (ITO-220AB only) from terminal to heat sink t =	1 min V _{AC}	15	00	V	

RoHS COMPLIANT HALOGEN

FREE

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT
Maximum instantaneous forward voltage per diode	V _F (1)	l _F = 15 A	T _J = 25 °C	0.82	- V
		l _F = 15 A	T _J = 125 °C	0.67	
		I _F = 30 A	T _J = 25 °C	0.93	
		I _F = 30 A	T _J = 125 °C	0.80	
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	5.0	μA
			T _J = 125 °C	6.0	mA

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width, \leq 40 ms

THERMAL CHARACTERISTICS ($T_c = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MB30H100CT	MF30H100CT	UNIT	
Typical thermal resistance per diode	$R_{ extsf{ heta}JC}$	1.9	4.6	°C/W	

ORDERING INFORMATION						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ITO-220AB	MF30H100CTHE3_B/P	1.99	Р	50/tube	Tube	
D ² PAK (TO-263AB)	MB30H100CTHM3/I	1.35	I	800/reel	Tape and reel	



MB30H100CT, MF30H100CT

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES ($T_C = 25$ °C unless otherwise noted)

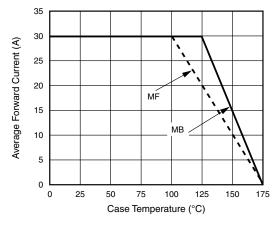


Fig. 1 - Forward Derating Curve Per Diode

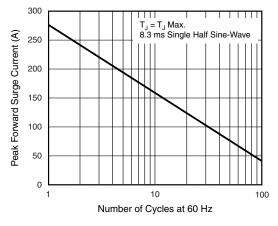
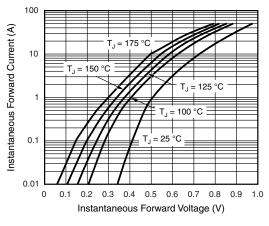
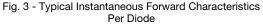


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





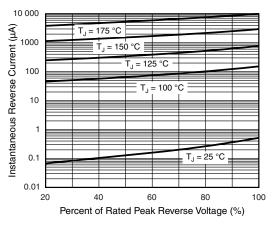


Fig. 4 - Typical Reverse Characteristics Per Diode

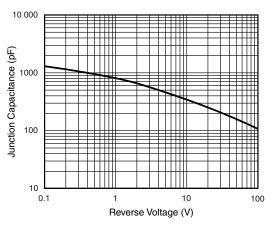


Fig. 5 - Typical Junction Capacitance Per Diode

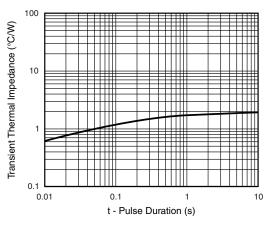


Fig. 6 - Typical Transient Thermal Impedance Per Diode

Revision: 22-Apr-2024

3

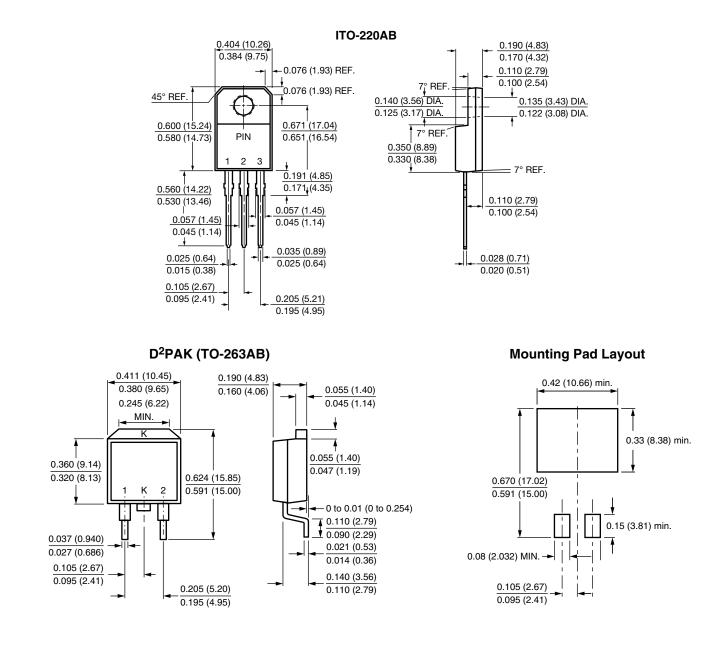
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



MB30H100CT, MF30H100CT

Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jul-2024